## NSN 5961-01-374-5995

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-374-5995 **Inclosure Material:** Plastic or ceramic **Overall Length:** Between 0.094 inches and 0.102 inches **Terminal Length:** Between 0.130 inches and 0.170 inches **Overall Height:** Between 0.034 inches and 0.050 inches **Overall Width:** Between 0.094 inches and 0.102 inches **Mounting Method: Terminal Features Provided:** Burn in and electrostatic sensitive and hermetically sealed case **Semiconductor Material:** Gallium arsenide Voltage Rating In Volts Per Characteristic: 22.0 breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes collector current, dc peak **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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